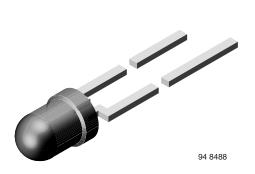
# VSLB3948



**Vishay Semiconductors** 

# High Speed Infrared Emitting Diode, 940 nm, GaAlAs, MQW



## DESCRIPTION

VSLB3948 is a high speed infrared emitting diode in GaAlAs, MQW technology, molded in a clear plastic package.

## FEATURES

- Package type: leaded
- Package form: T-1, clear epoxy
- Dimensions: Ø 3 mm
- High speed
- · High radiant power
- Low forward voltage
- · Suitable for high pulse current operation
- Angle of half intensity:  $\phi = \pm 22^{\circ}$
- Peak wavelength:  $\lambda_p = 940 \text{ nm}$
- · Good spectral matching to Si photodetectors
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **APPLICATIONS**

• Infrared remote control units

# PRODUCT SUMMARY COMPONENT I<sub>e</sub> (mW/sr) φ (°) λ<sub>p</sub> (nm) t<sub>r</sub> (ns) VSLB3948 65 ± 22 940 15

#### Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION							
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM				
VSLB3948	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1				

#### Note

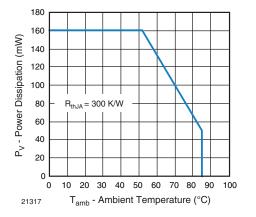
• MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Reverse voltage		V <sub>R</sub>	5	V			
Forward current		١ <sub>F</sub>	100	mA			
Peak forward current	$t_p/T = 0.1, t_p = 100 \ \mu s$	I <sub>FM</sub>	500	mA			
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1	А			
Power dissipation		Pv	160	mW			
Junction temperature		Tj	100	°C			
Operating temperature range		T <sub>amb</sub>	-25 to +85	°C			
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C			
Soldering temperature	$t \leq 5$ s, 2 mm from case	T <sub>sd</sub>	260	°C			
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R <sub>thJA</sub>	300	K/W			

Pb-free



# Vishay Semiconductors



www.vishay.com

Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

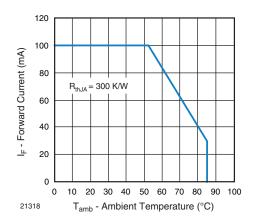


Fig. 2 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Forward voltage	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	V <sub>F</sub>	1.22	1.42	1.62	V	
Temperature coefficient of $V_F$	I <sub>F</sub> = 1 mA	TK <sub>VF</sub>		-1.5		mV/K	
Reverse current	$V_R = 5 V$	I <sub>R</sub>			10	μA	
Junction capacitance	$V_R = 0 V$ , f = 1 MHz, E = 0 mW/cm <sup>2</sup>	CJ		21		pF	
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	32	65	110	mW/sr	
Radiant power	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	φe		40		mW	
Temperature coefficient of radiant power	I <sub>F</sub> = 1 mA	ΤKφ <sub>e</sub>		-1.1		%/K	
	I <sub>F</sub> = 100 mA	ΤKφ <sub>e</sub>		-0.51		%/K	
Angle of half intensity		φ		± 22		0	
Peak wavelength	I <sub>F</sub> = 30 mA	λρ		940		nm	
Spectral bandwidth	I <sub>F</sub> = 30 mA	Δλ		30		nm	
Temperature coefficient of Ip	I <sub>F</sub> = 30 mA	ΤΚ <sub>λρ</sub>		0.25		nm	
Rise time	$I_F$ = 100 mA, 20 % to 80 %	t <sub>r</sub>		15		ns	
Fall time	$I_F$ = 100 mA, 20 % to 80 %	t <sub>f</sub>		15		ns	
Virtual source diameter		d		2		mm	



## **Vishay Semiconductors**

## **BASIC CHARACTERISTICS** ( $T_{amb} = 25 \text{ °C}$ , unless otherwise specified)

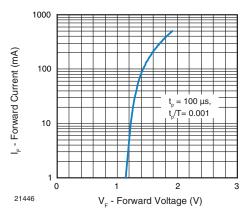


Fig. 3 - Forward Current vs. Forward Voltage

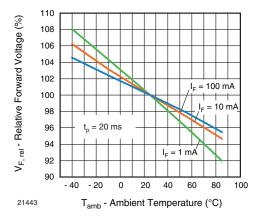


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

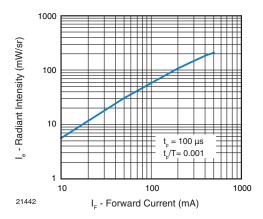


Fig. 5 - Radiant Intensity vs. Forward Current

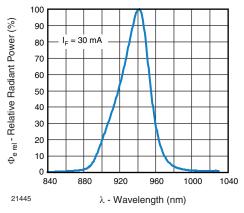


Fig. 6 - Relative Radiant Power vs. Wavelength

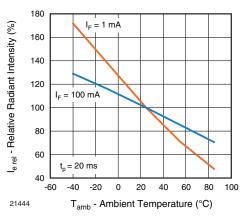


Fig. 7 - Relative Radiant Intensity vs. Ambient Temperature

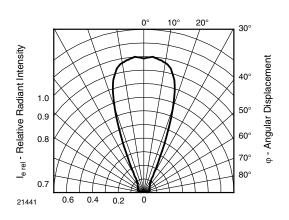


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

Rev. 1.5, 17-Mar-2025

3

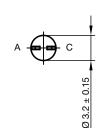
Document Number: 81876

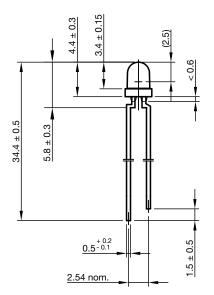
For technical questions, contact: <u>sensorstechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

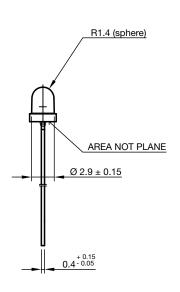


## **PACKAGE DIMENSIONS** in millimeters

Vishay Semiconductors









technical drawings according to DIN specifications

Drawing-No.: 6.544-5255.01-4 Issue: 9; 28.07.14



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2025 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2025

1